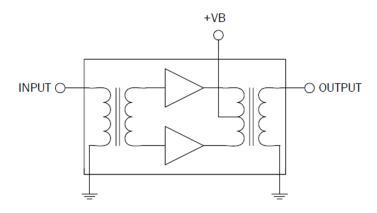


S10040220P12

GaAs Push Pull Hybrid 40MHz to 1000MHz

The S10040220P12 is a Hybrid Push Pull amplifier module. The part employs GaAs pHEMT die and GaAs MESFET die, and is operated from 40MHz to 1000MHz. It provides excellent linearity and superior return loss performance with low noise and optimal reliability.



Ordering Information

S10040220P12 Box with 50 Pieces

Absolute Maximum Ratings

Parameter	Rating	Unit
RF Input Voltage (single tone) (V _I)	75	dBmV
DC Supply Over-Voltage (5 minutes) (V _{OV})	15	V
Storage Temperature (T _{STG})	-40 to +100	°C
Operating Mounting Base Temperature (T _{MB})	-30 to +100	°C



Package: SOT-115J

Features

- Excellent Linearity
- Superior Return Loss Performance
- Extremely Low Distortion
- Optimal Reliability
- Extremely Low Noise
- Unconditionally Stable Under All Terminations
- 22dB Min. Gain at 1000MHz
- 450mA Max. at 12V_{DC}

Applications

 40MHz to 1000MHz CATV Amplifier Systems



Caution! ESD sensitive device.



RoHS (Restriction of Hazardous Substances): Compliant per EU Directive 2011/65/EU.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.



Nominal Operating Parameters

Parameter	Specification			Unit	Condision	
rarameter	Min	Тур	Max	Onit	Condition	
General Performance					$V+ = 12V; T_{MB} = 30^{\circ}C; Z_{S} = Z_{L} = 75\Omega$	
Power Gain	21.0	21.5	22.0	dB	f = 50MHz	
	22.0		23.5	dB	f = 1000MHz	
Slope ^[1]	0.5		2.0	dB	f = 40MHz to 1000MHz	
Flatness of Frequency Response			±0.4	dB	f = 40MHz to 1000MHz	
Input Return Loss	20.0			dB	f = 40MHz to 160MHz	
	18.0			dB	f = 160MHz to 870MHz	
	16.0			dB	f = 870MHz to 1000MHz	
	20.0			dB	f = 40MHz to 160MHz	
Output Return Loss	18.0			dB	f = 160MHz to 870MHz	
	15.0			dB	f = 870MHz to 1000MHz	
Noise Figure		2.5	3.5	dB	f = 50MHz to 1000MHz	
Total Current Consumption (DC)		430.0	450.0	mA		
Distortion Data 40MHz to 750MHz					$V+ = 12V; T_{MB} = 30^{\circ}C; Z_{S} = Z_{L} = 75\Omega$	
СТВ		-73	-71	dBc	V_o = 42.5dBmV; 112 channel flat ^[2]	
XMOD		-67	-65	dBc		
CSO		-70	-68	dBc		

^{1.} The slope is defined as the difference between the gain at the start frequency and the gain at the stop frequency.

 $Composite \ Second \ Order \ (CSO) \ - \ The \ CSO \ parameter \ (both \ sum \ and \ difference \ products) \ is \ defined \ by \ the \ NCTA.$

Composite Triple Beat (CTB) - The CTB parameter is defined by the NCTA.

Cross Modulation (XMOD) - Cross modulation (XMOD) is measured at baseband (selective voltmeter method), referenced to 100% modulation of the carrier being tested.

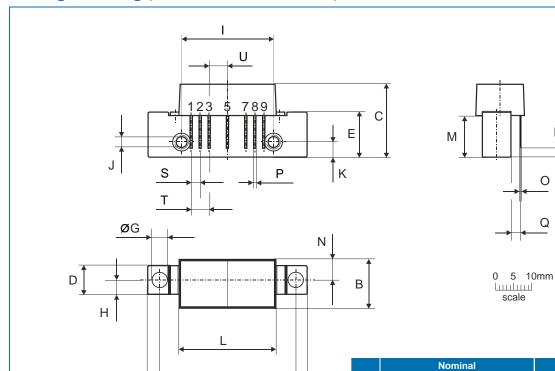
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 $^{2.\ 112\} channels,\ NTSC\ frequency\ raster:\ 55.25 MHz\ to\ 745.25 MHz,\ +42.5 dBmV\ flat\ output\ level.$



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Package Drawing (Dimensions in millimeters)



Notes:

European Projection



Pinning:

Pin	Name
1	Input
2-3	GND
4	
5	+VB
6	
7-8	GND
9	Output

	Nominal	·VIIII	IVICIA
Α	44,6 ^{± 0,2}	44,4	44,8
В	13,6 ^{± 0,2}	13,4	13,8
С	20,4 ^{± 0,5}	19,9	20,9
D	8 ^{± 0,15}	7,85	8,15
Е	12,6 ^{± 0,15}	12,45	12,75
F	38,1 ^{± 0,2}	37,9	38,3
G	4 +0,2 / -0,05	3,95	4,2
Н	4 ^{± 0,2}	3,8	4,2
1	25,4 ^{± 0,2}	25,2	25,6
J	UNC 6-32	-	-
K	4,2 ^{± 0,2}	4,0	4,4
L	27,2 ^{± 0,2}	27,0	27,4
М	11,6 ^{± 0,5}	11,1	12,1
N	5,8 ^{± 0,4}	5,4	6,2
0	0,25 ^{± 0,02}	0,23	0,27
Р	0,45 ^{± 0,03}	0,42	0,48
Q	2,54 ^{± 0,3}	2,24	2,84
R	2,54 ^{± 0,5}	2,04	3,04
S	2,54 ^{± 0,25}	2,29	2,79
Т	5,08 ^{± 0,25}	4,83	5,33
U	5,08 ^{± 0,25}	4,83	5,33

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